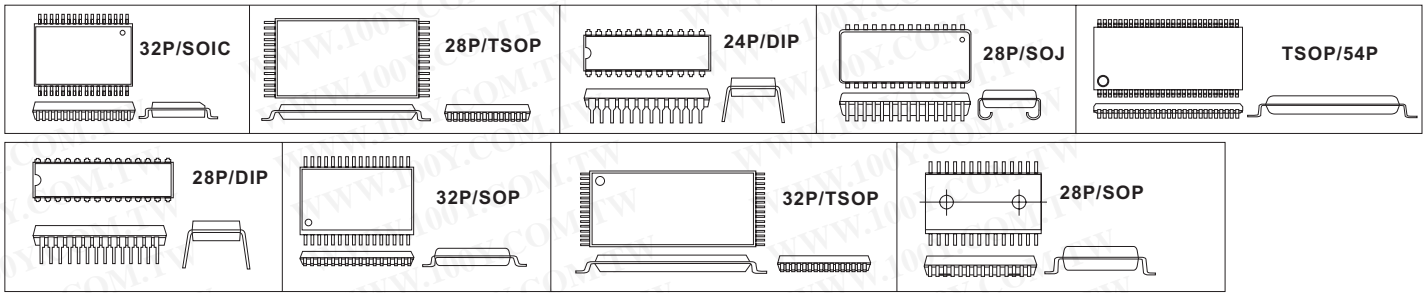


Memory IC

SRAM

Detailed product specifications are available on: us.100y.com.tw



Part No.	Product No.	Manufacturer	Description	Pin/Package	Size	Organisation	Access Time
19083	M5M51008FP-70L	MITSUBISHI	SRAM	32P/SOIC			70ns
19084	M5M5255DFP-70LL	MITSUBISHI	SRAM	28P/SOIC			70ns
1608	M5M5256CP-70LL	MITSUBISHI	SRAM	28P/DIP	256K	32K*8	70ns
19085	M5M5256DFP-10L	MITSUBISHI	SRAM	28P/SOIC			100ns
19090	M5M5256DFP-70LL	MITSUBISHI	SRAM	28P/SOIC			70ns
19091	M5M5256DVP-45LL	MITSUBISHI	SRAM	28P/TSOP			45ns
19092	MB84256C-70LLPFTN	FUJITSU	SRAM	TSOP			70ns
49536	MK48T02B-20	ST(SGS)	ST_CMOS 2K*8 TIMEKEEPER SRAM	DIP-24P		2K*8	200 ns
19097	MS6264CL-15FC	FUJITSU	SRAM	SOP			150ns
19098	MSM51257ALL-85RS	OKI Semi	SRAM	DIP			85ns
35488	MSM518221-30ZS	OKI Semi	2-Mbit, 256K*8-bit, Field Memory	28-pin ZIP	2M	256K*8	25 ns
40124	MSM51V8221A-30JS	OKI Semi	262.214-Word x 8-Bit Field Memory	400mil 28P/SOJ	2M	256K*8	30ns
23368	MT48LC4M16A2P-6	Micro-semi	64Mb SDRAM	54P/TSOP	64M	1Meg*16*4banks	6ns
35497	MT48LC4M16A2TG-75	Micro-semi	64Mb SDRAM	54P/TSOP	64M	1Meg*16*4banks	7.5ns
48504	P51256SL-07	INTEL	32K x 8 CMOS SLOW STATIC RAM	28P/DIP	256K	32K x 8	
40192	SRM2264LC		HIGH SPEED CMOS 64K-BIT STATIC RAM	28P/DIP			
1622	SRM2A256LC-70		SRAM	28P-DIP	256K	32K*8	85ns
19100	TC551001AFL-10LL	TOSHIBA	SRAM	SMD	1M		100ns
19101	TC551001BFL-70	TOSHIBA	SRAM	SMD			70ns
19102	TC55257DFL-70L	TOSHIBA	SRAM	SMD			70ns
19086	TMM2016BP-12		SRAM	DIP			120ns
19087	UM6116M-3L	UMC	SRAM	SMD			90ns
19088	UPD431000AGW-70LL	NEC	1M-BIT CMOS STATIC RAM	32P/SOP	1M	128K*8	70ns
19089	UPD431000AGZ-70LL-KJH	NEC	1M-SRAM	32P/TSOP	1M	131072*8Bits	70ns
1569	UPD43256BCZ-70LL	NEC	256K-BIT CMOS STATIC RAM 32K-WORD BY 8-BIT	28P/DIP	256K	32768*8	70ns
4090	UT621024PC-70LL	UTRON	SRAM	32P/SOP	1M	128K*8	70ns
19103	UT621024SC-70L	UTRON	128K X 8 BIT LOW POWER CMOS SRAM	32P/SOP	1M	128K*8	70ns
23622	UT62256CPC-70LL	UTRON	LOW POWER CMOS SRAM	28P/DIP	32K * 8		70ns
23623	UT62256CSC-70LL	UTRON	LOW POWER CMOS SRAM	28P/SOIC	32K*8	256K	70ns
22192	UT62256SC-70LL	UTC	32 K x 8 Bit low power CMOS SRAM	SOP-28 300mil	256K	32768*8	70ns
23145	V62C518256LL-70F	MOSEL-VIT.	STATIC RAM	28P/SOIC	32K * 8	256K	70ns
19104	V62C51864L-35P	MOSEL-VIT.	SRAM	28P/DIP			35ns
19105	V62C51864L-70P	MOSEL-VIT.	SRAM	28P/DIP			70ns
27907	W24257AJ-12		HIGH SPEED CMOS STATIC RAM	8P/SOJ	32K* 8	256K	12nS
23147	W24257AJ-15	WINBOND	HIGH SPEED CMOS STATIC RAM	8P/SOJ_300mil	32K* 8	256K	15nS
23148	W24257AK-15	WINBOND	HIGH SPEED CMOS STATIC RAM	28P/DIP	32K* 8	256K	15nS
19107	W24257S-100L	WINBOND	32K x 8 CMOS STATIC RAM	28P/SOP		32K*8	100ns
19106	W24257S-70L	WINBOND	32K x 8 CMOS STATIC RAM	28P/SOP		32K*8	70ns
14258	W24257S-70LL	WINBOND	32Kx8 CMOS STATIC RAM	28/SOP	256K	32768*8Bits	70ns
5379	W24258-70LL	WINBOND	32*8 normal speed, very low power CMOS static RAM	28P/DIP	256K	32768*8Bits	70ns
19108	W24258S-70LE	WINBOND	32K*8 CMOS STATIC RAM	28P/SOP		32K*8	70ns
15752	W24258S-70LL	WINBOND	32*8 normal speed, very low power CMOS static RAM	28P/SOP	32K* 8	32768*8Bits	70ns
1548	W2465S-70LL	WINBOND	8K x 8 CMOS STATIC RAM	28P/SOP	64K	8K*8	70ns
40621	W2465SG-7066	WINBOND	8K x 8 CMOS STATIC RAM	28P/SOP	64K	8K*8	70ns
15500	W24L11Q-70LE	WINBOND	128K x 8 CMOS STATIC RAM	32P/TSOP	128K*8	131072 x 8	70ns
40692	W24L257AJ-12	WINBOND	HIGH-SPEED CMOS STATIC RAM	28P/SOJ	32K* 8	256K	12nS
23149	W24L257AJ-15	WINBOND	HIGH-SPEED CMOS STATIC RAM	28P/SOJ	32K* 8	256K	15nS

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